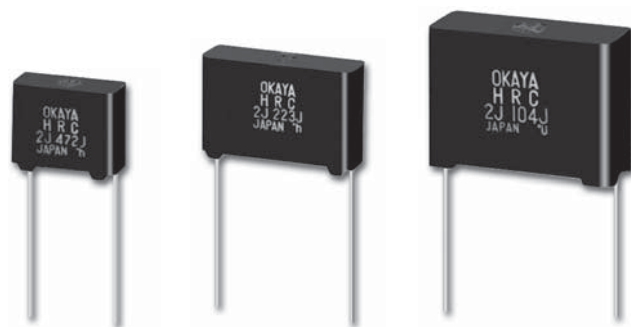


Features

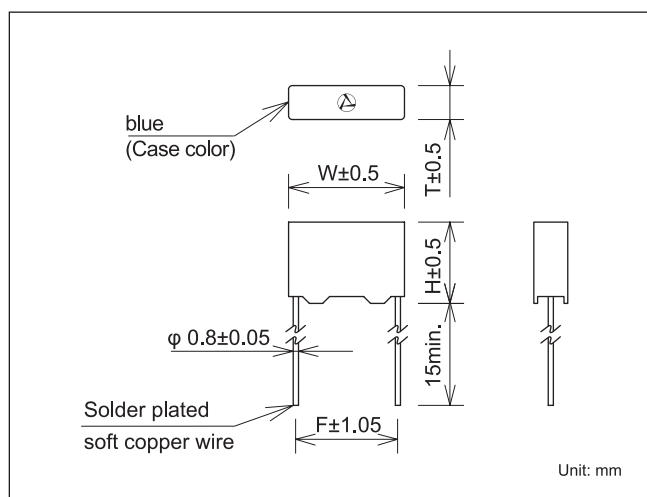
- Best for high frequency and high current.

Applications

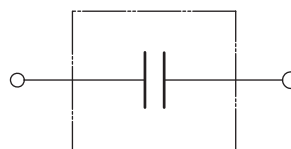
- High frequency resonant circuit, Resonant inverter circuit, Snubber circuit and Protection of semiconductors.



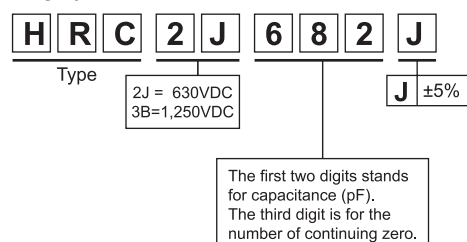
Dimensions



Circuit



- Model numbering system



Electrical Specifications

W·V		2J (630WV)				3B (1250WV)				Dissipation Factor	Test Voltage	Insulation Resistance
Capacitance		Dimensions (mm)				Dimensions (mm)						
PART NO.	μF±5%	W	T	H	F	W	T	H	F			
102	0.001	17.0	5.0	12.0	15.0	17.0	5.0	12.0	15.0	0.001max. (at 1k±100Hz)	WV×1.75 (2~5sec)	50,000MΩmin. (at 20°C 100VDC)
152	0.0015		5.5	12.5			5.5	12.5				
222	0.0022		6.5	13.5			6.5	13.5				
332	0.0033						8.0	15.0				
472	0.0047		8.0	15.0		6.5	16.0					
682	0.0068					10.0	19.5					
103	0.01	25.0	6.5	16.0	22.5	25.0	10.0	19.5	22.5			
153	0.015		8.0	15.0			11.0	22.0				
223	0.022		6.5	16.0	22.5	30.0	13.5	24.5	27.5			
333	0.033						8.0	17.5				
473	0.047	10.0	19.5	27.5	30.5	16.0	28.0	32.5				
683	0.068											
104	0.1											

Operating Temperature: -40~+85°C